Pb Free Product



NCE0224K

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE0224K uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. It can be used in a wide variety of applications.

General Features

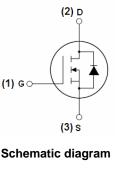
- V_{DS} =200V,I_D =24A $R_{DS(ON)} < 80 \text{m}\Omega$ @ $V_{GS} = 10 \text{V}$ (Typ:64m Ω)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAS
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% AVds TESTED!





Marking and pin assignment



TO-252 top view

Package Marking and Ordering Information

| - | | | | | | |
|---|----------------|----------|----------------|-----------|------------|----------|
| | Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
| | NCE0224K | NCE0224K | TO-252 | - | - | - |

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|--|------------------------|------------|------------|
| Drain-Source Voltage | V _{DS} | 200 | V |
| Gate-Source Voltage | V _G s | ±20 | V |
| Drain Current-Continuous | I _D | 24 | Α |
| Drain Current-Continuous(T _C =100°C) | I _D (100°C) | 17 | А |
| Pulsed Drain Current | I _{DM} | 100 | А |
| Maximum Power Dissipation | P _D | 150 | W |
| Single pulse avalanche energy (Note 5) | E _{AS} | 250 | mJ |
| Operating Junction and Storage Temperature Range | T_{J} , T_{STG} | -55 To 175 | $^{\circ}$ |

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Thermal Characteristic

| Thermal Resistance, Junction-to-Case ^(Note 2) | $R_{	heta JC}$ | 1 | °C/W | |
|--|----------------|---|------|--|
|--|----------------|---|------|--|

Electrical Characteristics (T_C=25 °C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|--|-----|------|------|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250μA 200 | | 220 | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =200V,V _{GS} =0V | - | - | 1 | μΑ |
| Gate-Body Leakage Current | I _{GSS} | V _{GS} =±20V,V _{DS} =0V | - | - | ±100 | nA |
| On Characteristics (Note 3) | | | • | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 2.5 | 3.2 | 4 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =10V, I _D =15A | - | 64 | 80 | mΩ |
| Forward Transconductance | g FS | V _{DS} =50V,I _D =15A | 30 | - | - | S |
| Dynamic Characteristics (Note4) | | | • | | | |
| Input Capacitance | C _{lss} | \\ 05\\\\ 05\\\\ | | 4200 | | PF |
| Output Capacitance | Coss | V_{DS} =25V, V_{GS} =0V, | | 163 | | PF |
| Reverse Transfer Capacitance | C _{rss} | F=1.0MHz | | 75 | | PF |
| Switching Characteristics (Note 4) | | | • | | | |
| Turn-on Delay Time | t _{d(on)} | | - | 10 | - | nS |
| Turn-on Rise Time | t _r | V _{DD} =100V,I _D =15A | - | 18 | - | nS |
| Turn-Off Delay Time | $t_{d(off)}$ | V_{GS} =10V, R_{GEN} =2.5 Ω | - | 22 | - | nS |
| Turn-Off Fall Time | t _f | | - | 5 | - | nS |
| Total Gate Charge | Qg | \/ 400\/ L 45A | | 60 | | nC |
| Gate-Source Charge | Q_{gs} | V_{DS} =100V, I_{D} =15A, V_{GS} =10V | | 19 | | nC |
| Gate-Drain Charge | Q_{gd} | V _{GS} =10V | | 17 | | nC |
| Drain-Source Diode Characteristics | | | • | | | |
| Diode Forward Voltage (Note 3) | V_{SD} | V _{GS} =0V,I _S =11A | - | - | 1.2 | V |
| Diode Forward Current (Note 2) | Is | - | - | - | 24 | А |
| Reverse Recovery Time | t _{rr} | TJ = 25°C, IF = 15A | - | 90 | - | nS |
| Reverse Recovery Charge | Qrr | $di/dt = 100A/\mu s^{(Note3)}$ | - | 300 | - | nC |
| Forward Turn-On Time | t _{on} | Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD) | | | | |

Notes:

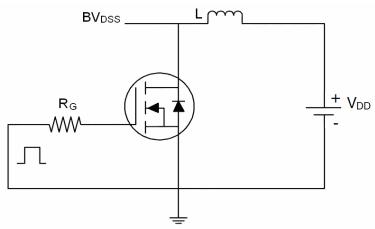
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V_{DD}=100V,V_G=10V,L=0.5mH,Rg=25 Ω



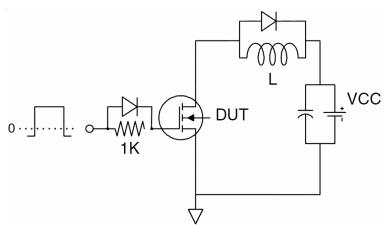
NCE0224K

Test Circuit

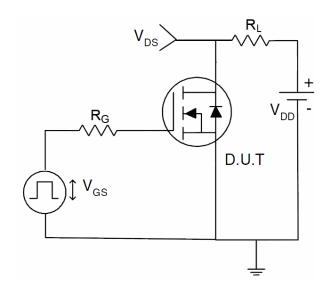
1) E_{AS} test Circuits



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

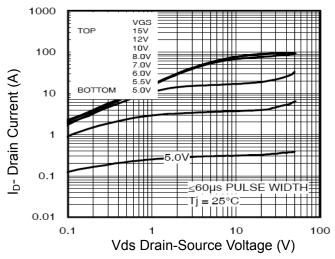


Figure 1 Output Characteristics

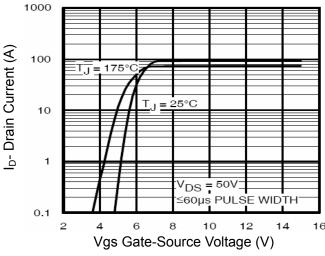


Figure 2 Transfer Characteristics

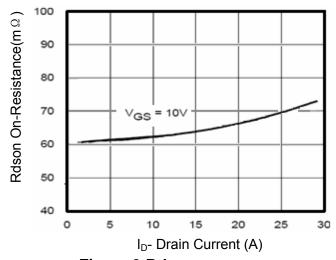


Figure 3 Rdson- Drain Current

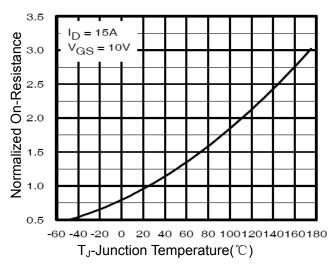


Figure 4 Rdson-JunctionTemperature

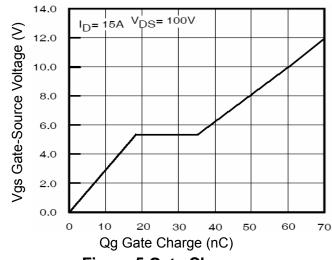


Figure 5 Gate Charge

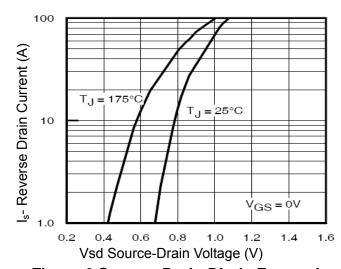


Figure 6 Source- Drain Diode Forward



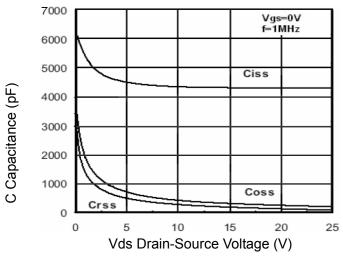


Figure 7 Capacitance vs Vds

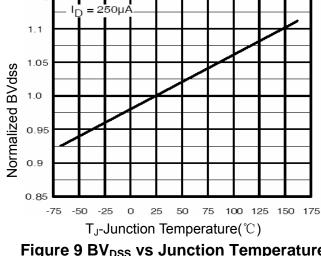


Figure 9 BV_{DSS} vs Junction Temperature

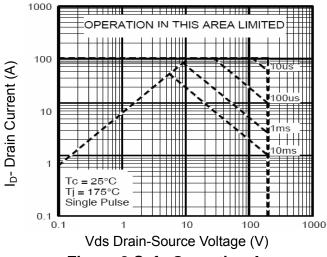


Figure 8 Safe Operation Area

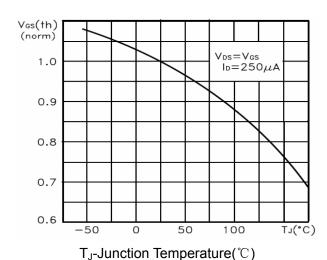


Figure 10 V_{GS(th)} vs Junction Temperature

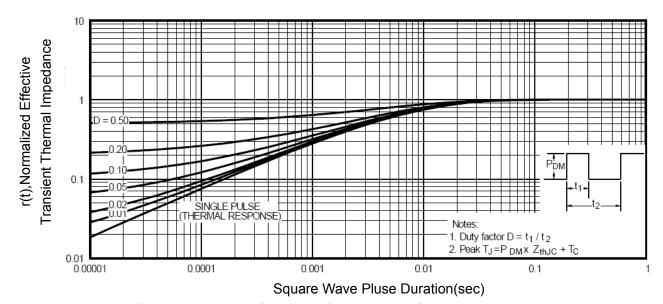


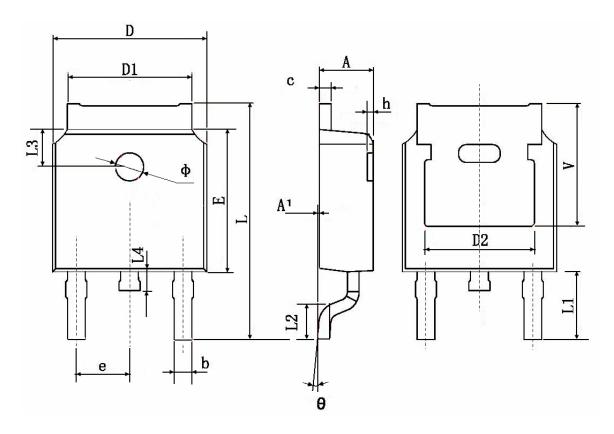
Figure 11 Normalized Maximum Transient Thermal Impedance

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TO-252 Package Information



| Symbol | Dimensions I | In Millimeters | Dimensions In Inches | | |
|--------|-----------------------|----------------|----------------------|--------|--|
| Symbol | Min. | Max. | Min. | Max. | |
| А | 2.200 | 2.400 | 0.087 | 0.094 | |
| A1 | 0.000 | 0.127 | 0.000 | 0.005 | |
| b | 0.660 | 0.860 | 0.026 | 0.034 | |
| С | 0.460 | 0.580 | 0.018 | 0.023 | |
| D | 6.500 | 6.700 | 0.256 | 0.264 | |
| D1 | 5.100 | 5.460 | 0.201 | 0.215 | |
| D2 | 4.83 | BO TYP. | 0.190 TYP. | | |
| Е | 6.000 | 6.200 | 0.236 | 0.244 | |
| е | 2.186 | 2.386 | 0.086 | 0.094 | |
| L | 9.800 | 10.400 | 0.386 | 0.409 | |
| L1 | 2.900 | 2.900 TYP. 0.1 | | 4 TYP. | |
| L2 | 1.400 | 1.700 | 0.055 | 0.067 | |
| L3 | 1.600 | TYP. | 0.063 | TYP. | |
| L4 | 0.600 | 1.000 | 0.024 | 0.039 | |
| Ф | 1.100 | 1.300 | 0.043 | 0.051 | |
| θ | 0° | 8° | 0° | 8° | |
| h | 0.000 | 0.300 | 0.000 | 0.012 | |
| V | 5.350 TYP. 0.211 TYP. | | | TYP. | |



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C3M0021120D DMN13M9UCA6-7 BSS340NWH6327XTSA1 MCM3400A-TP DMTH10H4M6SPS-13 IPS60R1K0PFD7SAKMA1

IPS60R360PFD7SAKMA1